

ABSTRACT

A semiconductor laser is disclosed with which
a VCSEL can be constituted with a simplified
configuration for optical transmission at a transmission
5 rate higher than 10 Gbps. The semiconductor laser
includes a resonator including a first active region able
to emit light in response to current injection and a
second active region able to emit light in response to
external excitation light. Multilayer film reflecting
10 mirrors sandwich the resonator from two opposite sides.
The first active region and the second active region
generate light at a wavelength the same as the resonance
mode of the resonator.